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November 2006

FDB8442 N-Channel PowerTrench[®] MOSFET

FAIRCHILD

SEMICONDUCTOR®

FDB8442

N-Channel PowerTrench[®] MOSFET

40V, 80A, 2.9mΩ

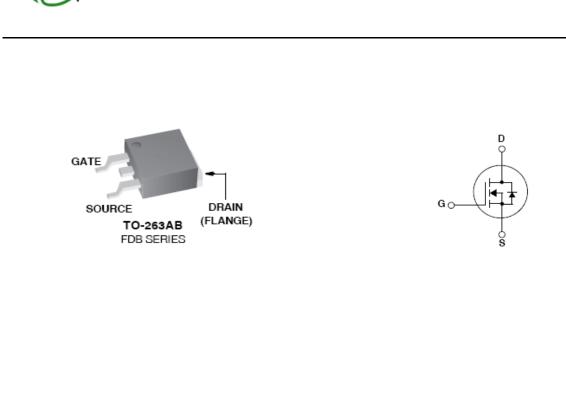
Features

- Typ $r_{DS(on)}$ = 2.1m Ω at V_{GS} = 10V, I_D = 80A
- Typ Q_{g(10)} = 181nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- RoHs Compliant

Applications

- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alernator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems





Symbol		Parameter					Ratings			Unite
V _{DSS}	Drain to So	Drain to Source Voltage						40		V
/ _{GS}	Gate to Source Voltage						±20		V	
	Drain Curre	_{as} = 10V)				80				
D	Drain Curre	_{mb} = 25°C, V	$V_{\rm GS}$ = 10V, with R _{θJA} = 43°C/W)				28			
	Pulsed	Pulsed						See Figure 4		
AS	Single Pulse Avalanche Energy			(Note 1))	720		
,	Power Dissipation						254			W/ºC
	Derate abo						1.7			
Γ _J , T _{STG}	Operating a	erature					-55 to +175			
herm	nal Char	acteristics								
R _{0JC}	Thermal Re	esistance Junction	to Case					0.59		°C/V
$R_{\theta JA}$	Thermal Resistance Junction to Ambient			0-263, lin ²	copper	pad area		43		°C/W
Packa	ge Marl	king and Ord	dering In	format	ion					
Device	Marking	Device	Package	e R	leel Siz	e Ta	ape Widt	h	Quan	tity
-		TO-263A	-		24mm		800 units			
	ical Cha	aracteristics	T _J = 25°C u					-		
Symbol		Parameter		Test	t Cond	itions	Min	Тур	Max	Units
Off Cha	aracterist	ics								
3 _{VDSS}	Drain to Sc	ource Breakdown V	oltage	I _D = 250μA	. Vas =	= 0V	40	-	-	V
				$V_{\rm DS} = 32V$			-	-	1	
DSS	Zero Gate	Voltage Drain Curr	ent	$V_{GS} = 0V$ $T_J = 150^{\circ}C$		-	-	250	μA nA	
GSS	Gate to So	urce Leakage Curr	ent	V _{GS} = ±20V			-	-		±100
)n Cha	reeterieti									
	aracteristi	CS								
V _{GS(th)}	S(th) Gate to Source Threshold Voltage			$V_{DS} = V_{GS}, I_D = 250 \mu A$			2	2.9	4	V
				I _D = 80A, V _{GS} = 10V			-	2.1	2.9	_
DS(on)	Drain to Source On Resistance		I _D = 80A, V _{GS} = 10V, T _J = 175°C			-	3.6	5.0	mΩ	
Dynam	ic Charac	teristics					•			
C _{iss}	Input Capacitance Output Capacitance Reverse Transfer Capacitance					-	12200	-	pF	
C _{oss}			$V_{DS} = 25V, V_{GS} = 0V,$		-	1040	-	pF		
Crss			е	f = 1MHz		-	640	-	pF	
R _G	Gate Resistance			V _{GS} = 0.5V, f = 1MHz		I.	1.0	-	Ω	
	Total Gate Charge at 10V			$\begin{tabular}{ c c c c c } \hline V_{GS} &= 0 \mbox{ to } 10V \\ \hline V_{GS} &= 0 \mbox{ to } 2V \\ \hline I_{D} &= 80A \end{tabular}$		-	181	235	nC	
С _{g(TOT)}	Threshold Gate Charge Gate to Source Gate Charge					V _{DD} = 20V	-	23	30	nC
U \ /						-	49	-	nC	
Q _{g(TH)}	Gate to So	aree date enarge		l _g = 1mA				1		
Q _{g(TOT)} Q _{g(TH)} Q _{gs} Q _{gs2} Q _{gd}	Gate Char	ge Threshold to Pla ain "Miller" Charge	iteau			$I_g = 1 \text{mA}$	-	26	-	nC nC

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switchi	ng Characteristics					
t _(on)	Turn-On Time		-	-	62	ns
t _{d(on)}	Turn-On Delay Time		-	19.5	-	ns
t _r	Turn-On Rise Time	$V_{DD} = 20V, I_{D} = 80A$	-	19.3	-	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 2\Omega$	-	57	-	ns
t _f	Turn-Off Fall Time		-	17.2	-	ns
t _{off}	Turn-Off Time		-	-	118	ns
	ource Diode Characteristics	1		-		
V _{SD}	Source to Drain Diode Voltage	$I_{SD} = 80A$	-	0.9	1.25	V
-		I _{SD} = 40A	-	0.8	1.0	V
t _{rr}	Reverse Recovery Time	I _F = 75A, di/dt = 100A/μs	-	49	64	ns

I_F = 75A, di/dt = 100A/μs

Q_{rr}

Notes: 1: Starting $T_J = 25^{\circ}C$, L = 0.35mH, I_{AS} = 64A 2: Pulse width = 100s.

Reverse Recovery Charge

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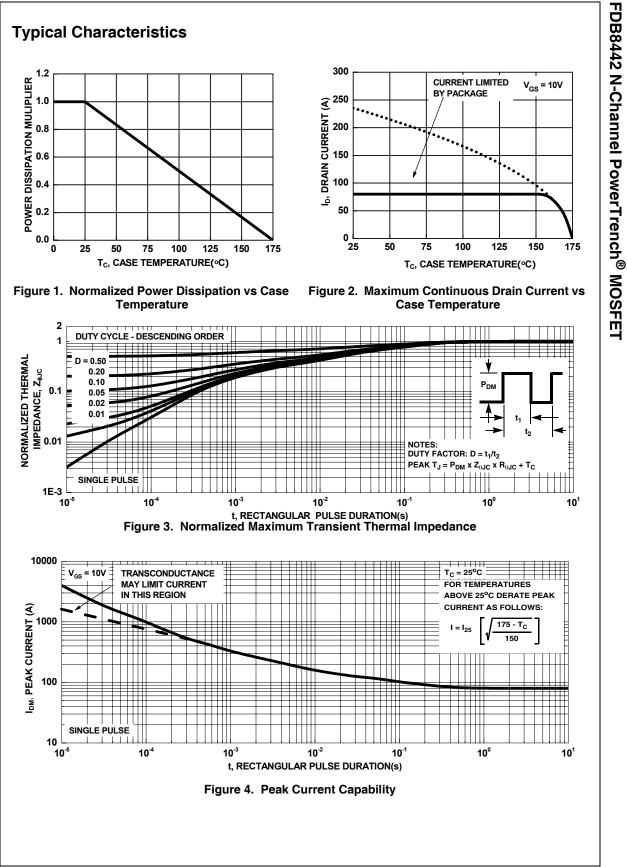
nC

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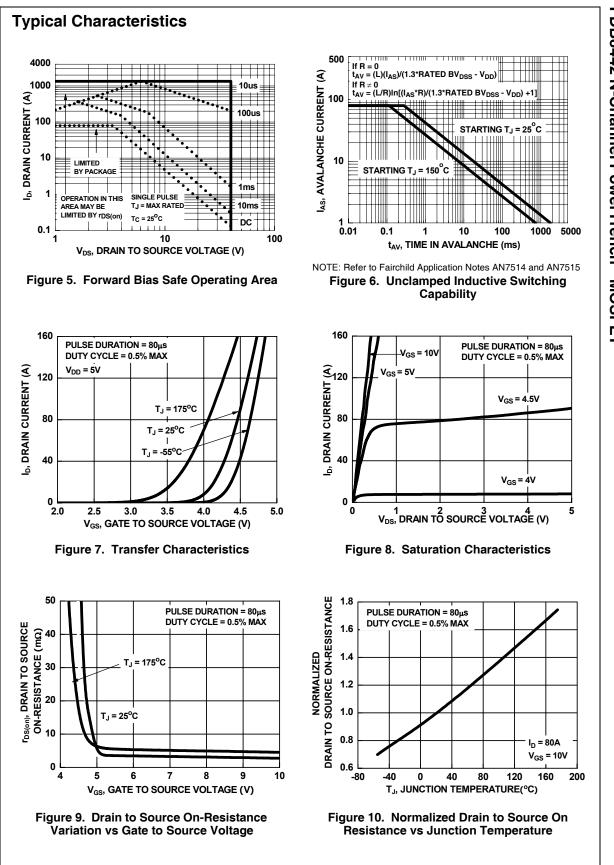
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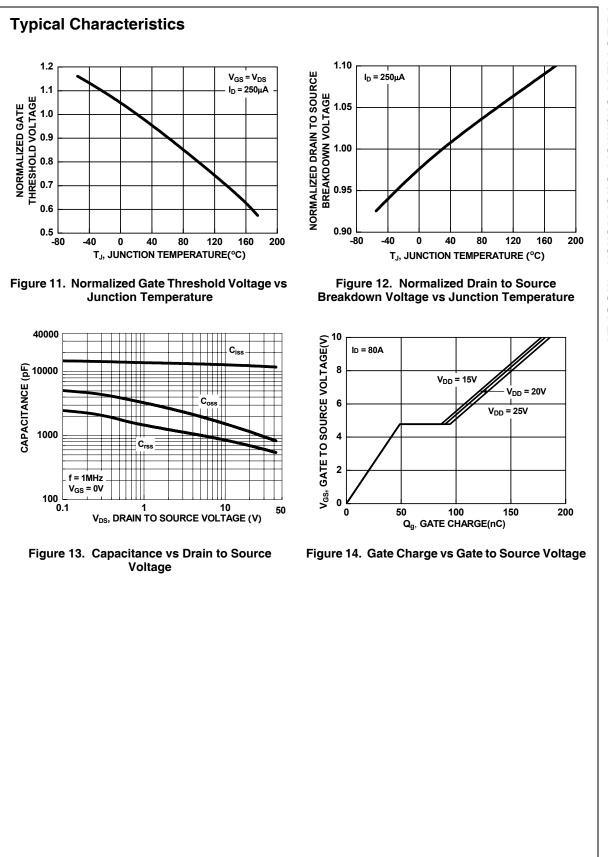
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